

# 國立臺北科技大學 101 學年度碩士班招生考試

系所組別：2230 電腦與通訊研究所丙組

## 第二節 電子學 試題

第一頁 共二頁

### 注意事項：

1. 本試題共 6 題，配分共 100 分。
2. 請標明大題、子題編號作答，不必抄題。
3. 全部答案均須在答案卷之答案欄內作答，否則不予計分。

(請依序於答案卷之答案欄內作答)

1. An amplifier exhibits two poles at 100 MHz and 10 GHz, and a zero at 1 GHz. Construct the Bode plot of  $|V_{out}/V_m|$ . (10%)
2. We wish to design the MOS cascode of Fig. 1 for an output impedance of 200 k $\Omega$  and bias current of 0.5 mA. Assume that, for each transistor, the threshold voltage  $V_{th} = 0.4$  V,  $\mu_n C_{ox} = 100$   $\mu\text{A}/\text{V}^2$ , the channel length modulation coefficient  $\lambda = 0.1$   $\text{V}^{-1}$ , and the transistor aspect ratio  $(W/L)_1 = (W/L)_2$ .
  - (a) Determine  $(W/L)_1$ . (10%)
  - (b) Calculate the required value of  $V_{b2}$ . (10%)

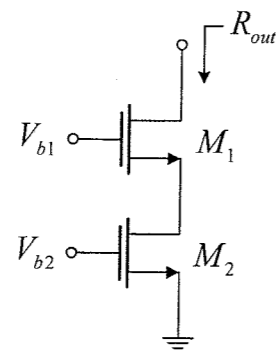


Fig. 1

3. We wish to design the MOS cascode of Fig. 2 for an input pole of 5 GHz and an output pole of 10 GHz. Assume  $M_1$  and  $M_2$  are identical, the overdrive voltage  $(V_{GS} - V_{th})$  for each transistor is 200 mV,  $I_D = 0.5$  mA,  $C_{GS} = (2/3)WLC_{ox}$ ,  $L = 0.18$   $\mu\text{m}$ ,  $C_{ox} = 12$  fF/ $\mu\text{m}^2$ ,  $\mu_n C_{ox} = 100$   $\mu\text{A}/\text{V}^2$ ,  $\lambda = 0$ , and  $C_{GD} = C_0 W$ , where  $C_0 = 0.2$  fF/ $\mu\text{m}$  denotes the gate-drain capacitance per unit width.
  - (a) Determine the channel width  $W$  of each transistor ( $M_1$  and  $M_2$  are identical). (5%)
  - (b) Use Miller's approximation for  $C_{GD2}$  to determine the maximum allowable values of  $R_G$ ,  $R_D$ . (10%)
  - (c) Determine the voltage gain. (5%)

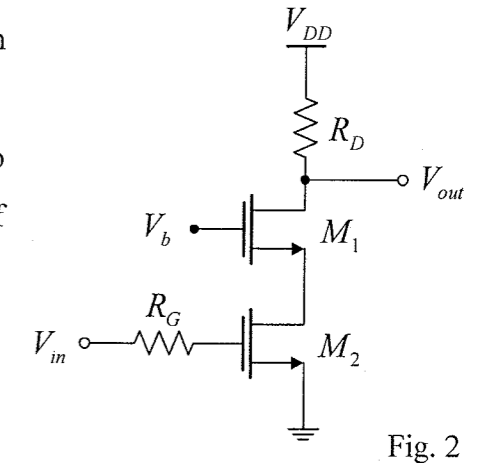


Fig. 2

4. Design a common-base stage shown with Fig. 3 for a voltage gain of 10, and an input impedance of 50  $\Omega$ . Assume  $I_S = 5 \times 10^{-16}$  A,  $V_T = 26$  mV,  $V_A = \infty$ ,  $\beta = 100$ , and  $V_{CC} = 2.5$  V. Besides, the resistance  $R_E$  is given as 500  $\Omega$  and the current through  $R_2$  is 11 times of the current through the transistor base.
  - (a) Determine  $R_C$ ,  $R_1$ , and  $R_2$ . (12%)
  - (b) If this amplifier is used at the receiver front-end of a 900 MHz cell phone. Compute  $C_1$  and  $C_B$ . (8%)

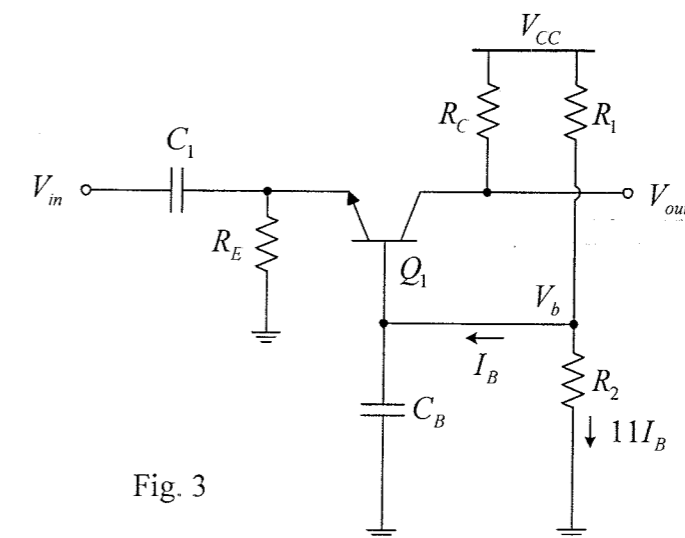


Fig. 3

注意：背面尚有試題

5. A differential amplifier is illustrated in Fig. 4. For simplicity, assume  $M_1$  and  $M_2$  are identical and neglect channel-length modulation in  $M_1$  and  $M_2$ . Show the common-mode rejection ratio (CMRR) of this amplifier is

$$CMRR = (1 + 2g_{m1}r_{o3}) \frac{R_D}{\Delta R_D}$$

where  $g_{m1}$  is the transconductance of  $M_1$  and  $r_{o3}$  is the output impedance of  $M_3$ . (15 %)

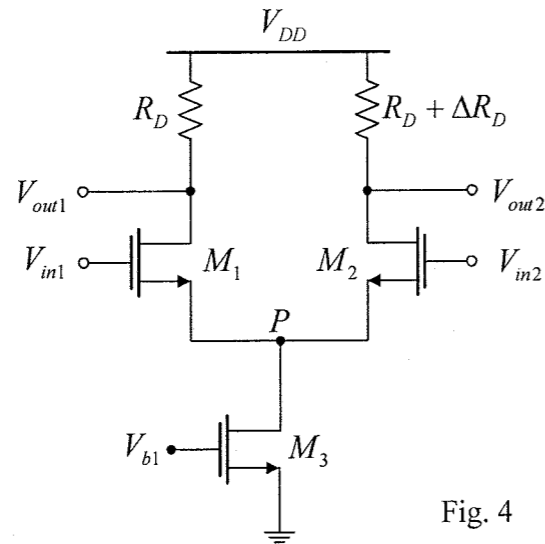


Fig. 4

6. Fig. 5 is an active filter. Assume the gain of the op-amp is very large, please:
- Compute the response of the circuit, i.e.,  $H(s) = V_{out}(s)/V_{in}(s)$ . (5 %)
  - Show the Bode plot when  $R_1C_1 < R_2C_2$ . (5 %)
  - Show the Bode plot when  $R_1C_1 > R_2C_2$ . (5 %)

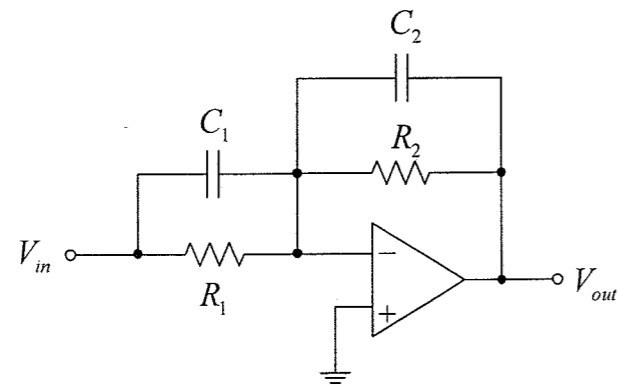


Fig. 5